



Модуль диодный

МДД-300-18



Средний прямой ток							I _{FAV}	300A					
Повторяющееся импульсное обратное напряжение							U _{RRM}	400 - 1800В					
U _{RRM} , В	400	500	600	700	800	900	1000	1200	1400	1600	1800		
Класс по напряжению	4	5	6	7	8	9	10	12	14	16	18		
T _j , °C	-60 ÷ 150												

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _C =100°C	150			300	A
I _{F(RMS)}	RMS forward current		150			471	A
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RsM} = V _{RRM} +100V	150	400		1800	V
I _{RRM}	Repetitive peak current	at V _{RRM}	150			20	mA
I _{FSM}	Surge forward current	10ms half sine wave V _R =0.6V _{RRM}	150			10	KA
I ² t	I ² T for fusing coordination					500	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.75	V
r _F	Forward slop resistance					0.55	mΩ
V _{FM}	Peak forward voltage	I _{FM} =900A	25			1.35	V
R _{th(j-c)}	Thermal resistance Junction to case	At 180° sine Single side cooled				0.130	°C /W
R _{th(c-h)}	Thermal resistance case to heatsink	At 180° sine Single side cooled				0.04	°C /W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I _{iso} :1mA(max)	2500				V
F _m	Terminal connection torque(M8)				12		N·m
	Mounting torque(M6)				6		N·m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				860		g
Outline	MTD3						

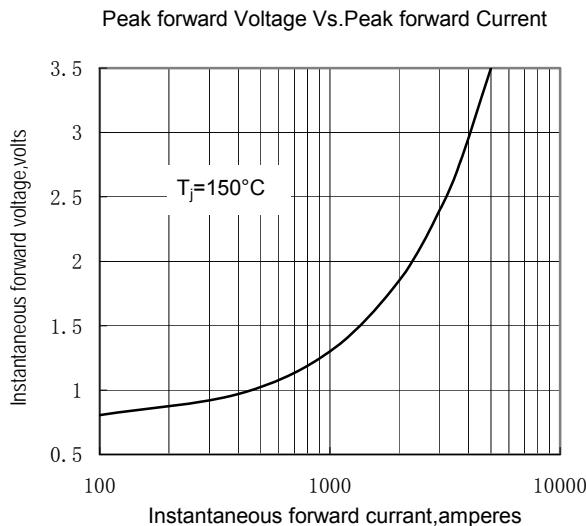


Fig.1

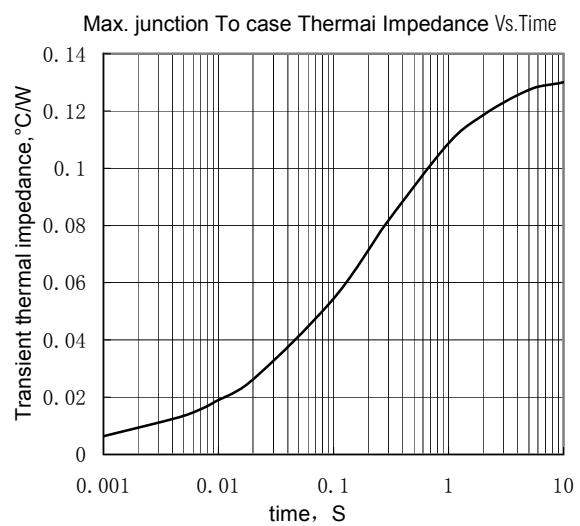


Fig.2

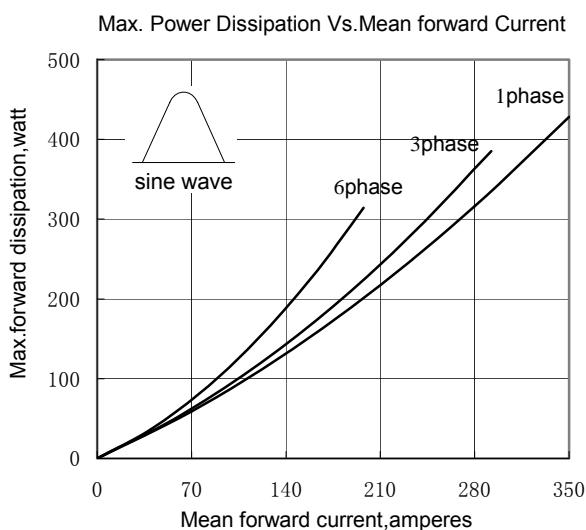


Fig.3

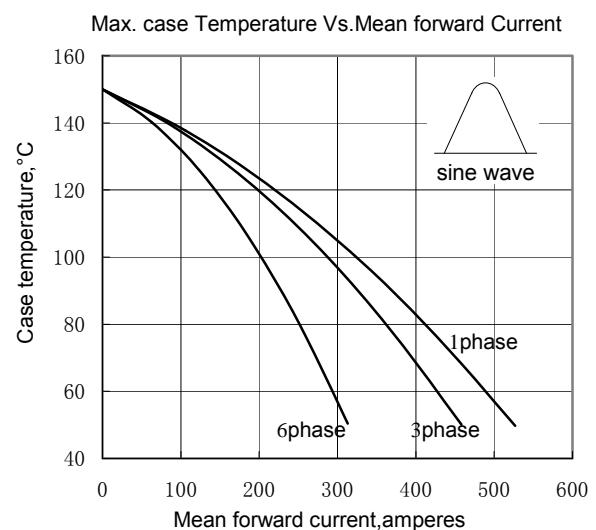


Fig.4

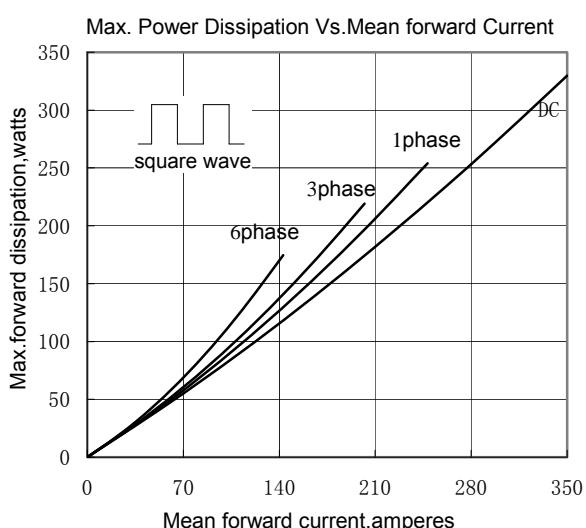


Fig.5

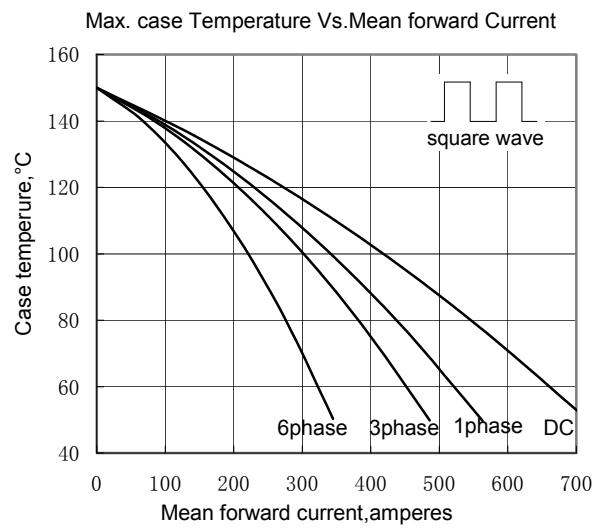


Fig.6

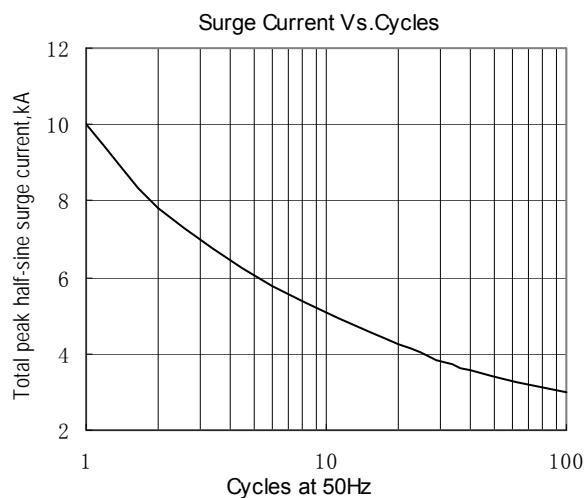


Fig.7

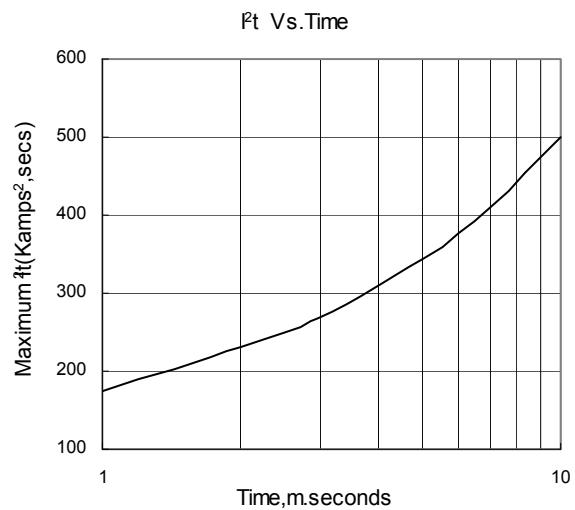
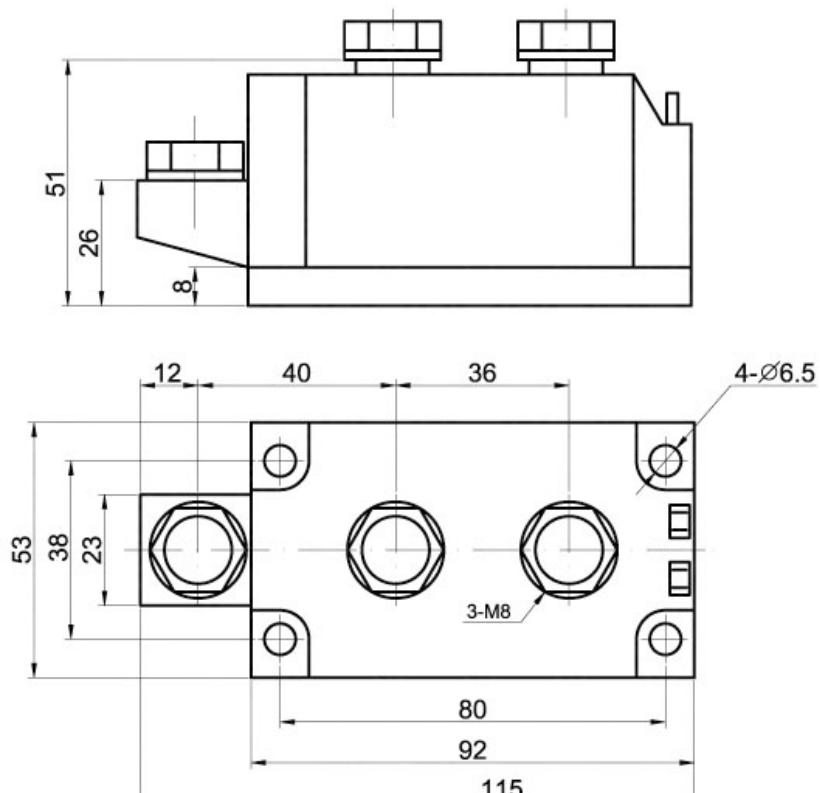


Fig.8

ГАБАРИТНЫЕ РАЗМЕРЫ

Тип корпуса: MDT3



Все размеры в миллиметрах



1–Анод/Катод, 2 –Катод, 3- Анод